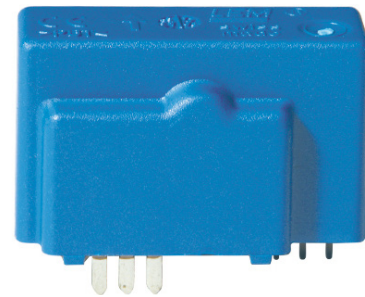


Current Transducer LH 50-P

$I_{PN} = 50 A$

For the electronic measurement of current: DC, AC, pulsed..., with galvanic separation between the primary and the secondary circuit.



Features

- Closed loop (compensated) current transducer
- PCB mounting
- Current output.

Advantages

- High accuracy
- Very low offset
- Very low offset drift over temperature.

Applications

- AC variable speed and servo motor drives
- Static converters for DC motor drives
- Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications
- Solar inverters.

Standards

- IEC 61800-1: 1997
- IEC 61800-2: 2015
- IEC 61800-3: 2004
- IEC 61800-5-1: 2007
- IEC 62109-1: 2010
- IEC 62477-1: 2012
- UL 508: 2013.

Application Domain

- Industrial.

Absolute maximum ratings

| Parameter | Symbol | Unit | Value |
|--|-----------|------|-------------|
| Maximum supply voltage (working) (-40 ... 85 °C) | $\pm U_C$ | V | ± 15.75 |
| Primary conductor temperature | T_B | °C | 100 |
| Maximum steady state primary current (-40 ... 85 °C) | I_{PN} | A | 50 |

Stresses above these ratings may cause permanent damage.
Exposure to absolute maximum ratings for extended periods may degrade reliability.

UL 508: Ratings and assumptions of certification

File # E189713 Volume: 2 Section: 10

Standards

- USR indicates investigation to the Standard for Industrial Control Equipment UL 508.
- CNR indicates investigation to the Canadian standard for Industrial Control Equipment CSA C22.2 No. 14-13

Conditions of acceptability

When installed in the end-use equipment, with primary feed through potential involved of 600 V AC/DC, consideration shall be given to the following:

- 1 - These products must be mounted in a suitable end-use enclosure.*
- 2 - The secondary pin terminals have not been evaluated for field wiring.*
- 3 - Low voltage control circuit shall be supplied by an isolating source (such as transformer, optical isolator, limiting impedance or electro-mechanical relay).*
- 4 - Based on the temperature test performed on all series, the primary bar or conductor shall not exceed 100 °C in the end use application.*

Marking

Only those products bearing the UL or UR Mark should be considered to be Listed or Recognized and covered under UL's Follow-Up Service. Always look for the Mark on the product.

Insulation coordination

| Parameter | Symbol | Unit | Value | Comment |
|--|-----------------------------------|------------|----------|--|
| RMS voltage for AC insulation test, 50 Hz, 1 min | U_d | kV | 5 | |
| Impulse withstand voltage 1.2/50 μ s | U_{Ni} | kV | 12 | |
| Insulation resistance | R_{INS} | G Ω | ≥ 1 | measured at 500 V DC |
| Partial discharge extinction RMS voltage @ 10 pC | U_t | kV | > 2 | |
| Comparative tracking index | CTI | | 600 | |
| Application example | | V | 300 | Reinforced insulation, non uniform field according to IEC 61800-5-1 CAT III, PD2 |
| Application example | | V | 1000 | Basic insulation, non uniform field according to IEC 61800-5-1 CAT III, PD2 |
| Case material | - | - | V0 | According to UL 94 |
| Clearance and creepage | See dimensions drawing on page 11 | | | |

Environmental and mechanical characteristics

| Parameter | Symbol | Unit | Min | Typ | Max | Comment |
|-------------------------------|------------------|--------------|-----|-----|-----|---------|
| Ambient operating temperature | T_A | $^{\circ}$ C | -40 | | 85 | |
| Ambient storage temperature | $T_{A\text{st}}$ | $^{\circ}$ C | -50 | | 90 | |
| Mass | m | g | | 23 | | |

Electrical data

At $T_A = 25\text{ °C}$, $\pm U_C = \pm 15\text{ V}$, $R_M = 1\ \Omega$, unless otherwise noted.

Lines with a * in the conditions column apply over the $-40 \dots 85\text{ °C}$ ambient temperature range.

| Parameter | Symbol | Unit | Min | Typ | Max | Conditions |
|---|---------------------|-----------------|-----------------|------------|-------------|--|
| Primary nominal RMS current | I_{PN} | A | | 50 | | * |
| Primary current, measuring range | I_{PM} | A | -110 | | 110 | * With $R_M \leq 20\ \Omega$ |
| Measuring resistance | R_M | Ω | 0 ¹⁾ | | | * Measuring resistance range is defined in figure 1, 2 |
| Secondary nominal RMS current | I_{SN} | mA | -25 | | 25 | * |
| Resistance of secondary winding | R_S | Ω | | | 94 | $R_S(T_A) = R_S \times (1 + 0.004 \times (T_A + \Delta\text{temp} - 25))$ Estimated temperature increase @ I_{PN} is $\Delta\text{temp} = 15\text{ °C}$ |
| Secondary current | I_S | mA | -55 | | 55 | * |
| Number of secondary turns | N_S | | | 2000 | | |
| Theoretical sensitivity | | mA/A | | 0.5 | | |
| Supply voltage | $\pm U_C$ | V | ± 11.4 | | ± 15.75 | * |
| Current consumption | I_C | mA | | 20 21 | | $\pm U_C = \pm 12\text{ V}$ $\pm U_C = \pm 15\text{ V}$ |
| Offset current referred to primary | I_O | A | -0.12 | | 0.12 | |
| Offset current referred to secondary | | mA | -0.060 | | 0.060 | |
| Overall I_O at $-40 \dots 85\text{ °C}$, referred to primary | \bar{I}_{Oov} | A | -0.18 | | 0.18 | * |
| Overall I_O at $-40 \dots 85\text{ °C}$, referred to secondary | | mA | -0.09 | | 0.09 | * |
| Temperature coefficient of I_{OE} referred to primary | TCI_{OE} | $\mu\text{A/K}$ | -400 | | 400 | * |
| Magnetic offset current, after overload referred to secondary | I_{OM} | mA | | ± 0.04 | | After $5 \times I_{PN}$ |
| Sensitivity error | ε_S | % | -0.2 | | 0.2 | * |
| Temperature coefficient of S | TCS | ppm/K | -30 | | 30 | * |
| Linearity error | ε_L | % of I_{PN} | -0.1 | | 0.1 | * |
| Total error at I_{PN} | ε_{tot} | % | | | 0.4 | * |
| Error at I_{PN} | ε | % | | | 0.2 | * |
| RMS noise current referred to primary | I_{no} | mA | | 18 | | 1 Hz to 100 kHz (see figure 4) |
| Delay time to 10 % of the final output value for I_{PN} step | t_{D10} | ns | | 200 | | 0 to 100 A, 50 A/ μs $R_M = 10\ \Omega$ |
| Delay time to 90 % of the final output value for I_{PN} step | t_{D90} | ns | | 500 | | 0 to 100 A, 50 A/ μs , $R_M = 10\ \Omega$ (figure 3); PCB design defined in fig.7 |
| Delay time to 90 % of the final output value for I_{PN} step | t_{D90} | ns | | 100 | | 0 to 100 A, 50 A/ μs , $R_M = 10\ \Omega$; PCB design defined in fig. 6 |
| Frequency bandwidth | BW | kHz | | 200 | | $R_M = 10\ \Omega$; -3 dB |

Note: 1) With $\pm 15\text{ V} \pm 5\%$ as power supply, $T_A = 85\text{ °C}$ and I_{PN} (DC value).

Other values of minimum values according to conditions of use are given in Figure 1, 2.

Typical performance characteristics

Definition of typical, minimum and maximum values

Minimum and maximum values for specified limiting and safety conditions have to be understood as such as well as values shown in “typical” graphs. On the other hand, measured values are part of a statistical distribution that can be specified by an interval with upper and lower limits and a probability for measured values to lie within this interval.

Unless otherwise stated (e.g. “100 % tested”), the LEM definition for such intervals designated with “min” and “max” is that the probability for values of samples to lie in this interval is 99.73 %.

For a normal (Gaussian) distribution, this corresponds to an interval between -3 sigma and +3 sigma. If “typical” values are not obviously mean or average values, those values are defined to delimit intervals with a probability of 68.27 %, corresponding to an interval between -sigma and +sigma for a normal distribution.

Typical, minimum and maximum values are determined during the initial characterization of the product.

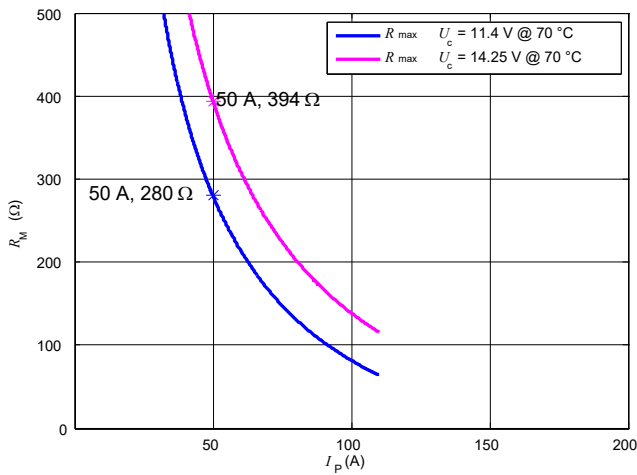


Figure 1: Maximum measuring resistance @ 70 °C in DC

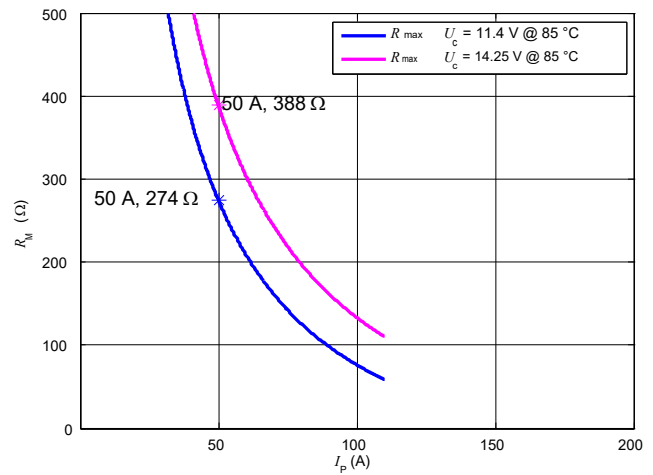


Figure 2: Maximum measuring resistance @ 85 °C in DC

$$R_{M \max} = N_S \times \frac{U_{C \min} - 1.5 \text{ V}}{I_p} - R_{S \max}$$

The measuring resistance (R_M) has to be properly defined in order to guarantee the optimal transducer performance. Maximum measuring resistance ($R_{M \max}$) is based on the maximum current that must be measured by the transducer. The simple formula $R_{M \max}$ is shown above.

Minimum measuring resistance ($R_{M \min}$) is based on the maximum heat dissipation capacity of the transducer. It depends on the following working conditions: supply voltage U_C , ambient temperature T_A and the nominal primary rms current (I_{PN}).

Minimum R_M value can be as low as 0 Ω , and this is normally the case when the transducer is supplied with a low supply voltage $U_C = \pm 12 \text{ V}$.

In figure 1 the minimum R_M value data is omitted whenever it is equal to 0 Ω .

Typical performance characteristics

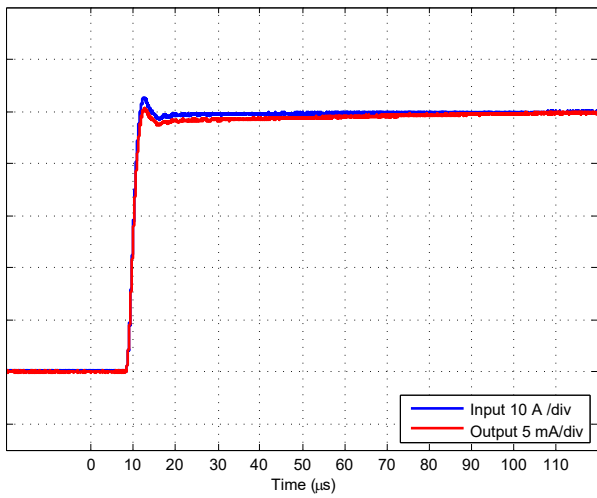


Figure 3: Typical delay time (0 to 50 A, 50 A/μs with $R_M = 10 \Omega$)

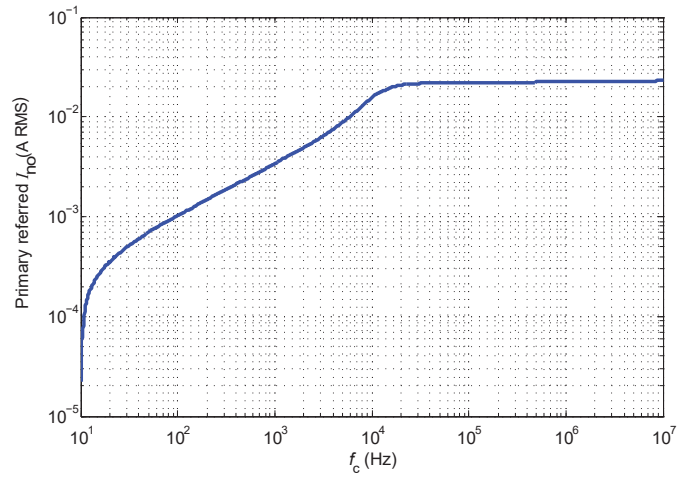


Figure 4: Typical total RMS current noise (Primary referred I_{no} (A RMS) with $R_M = 10 \Omega$)

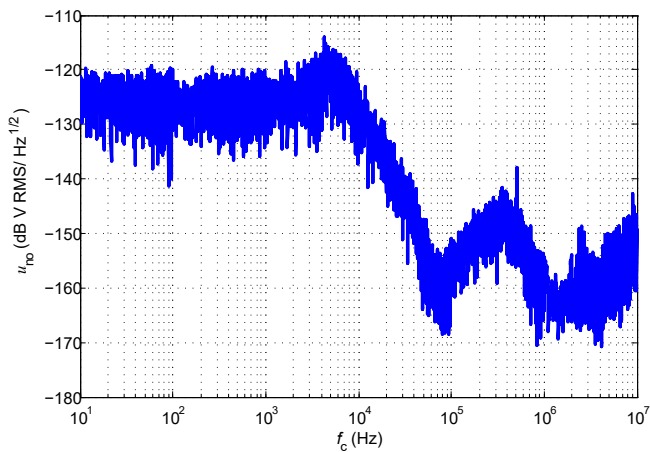


Figure 5: Typical noise voltage spectral density u_{no} with $R_M = 10 \Omega$

High and low speed PCB designs

The PCB design is very important to achieve good response to high-frequency primary current in terms of accuracy and bandwidth. High speed PCB design, as the one shown here below, allows the transducer to obtain lower delay times to high varying primary current. In order to achieve the highest bandwidth possible the loop of the primary current traces at the transducer back should be as tight as possible.

On the other hand, high speed PCB design requires more PCB area for the primary current traces compared to low speed PCB design. The customer must define the optimal PCB design according to the application specifications.

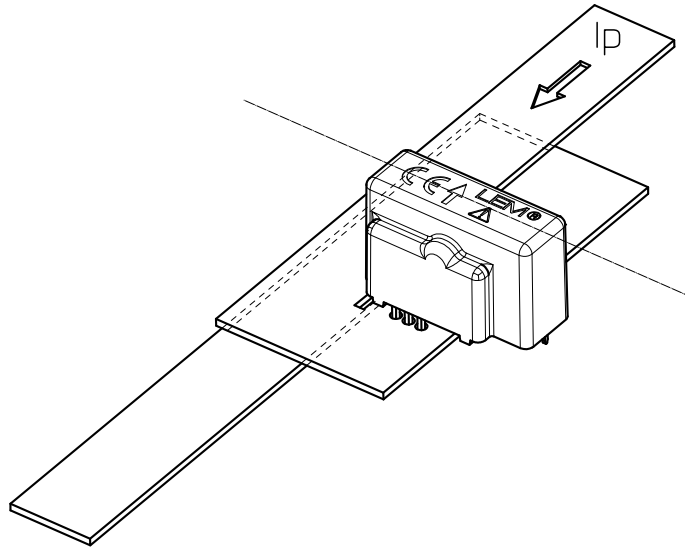


Figure 6: High speed PCB design

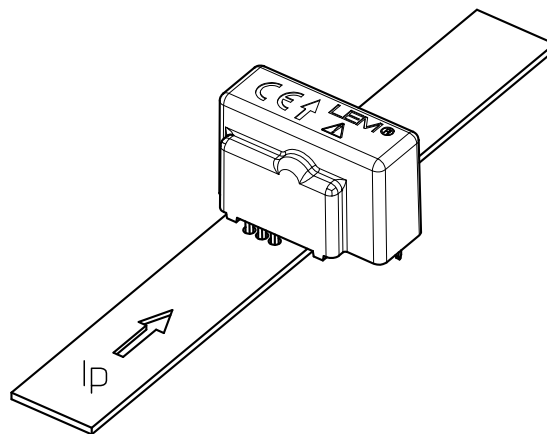


Figure 7: Low speed PCB design

Performance parameters definition

Ampere-turns and amperes

The transducer is sensitive to the primary current linkage Θ_p (also called ampere-turns).

$$\Theta_p = N_p \cdot I_p \text{ (At)}$$

Where N_p is the number of primary turn (depending on the connection of the primary jumpers)

Caution: As most applications will use the transducer with only one single primary turn ($N_p = 1$), much of this datasheet is written in terms of primary current instead of current linkages. However, the ampere-turns (At) unit is used to emphasize that current linkages are intended and applicable.

Transducer simplified model

The static model of the transducer at temperature T_A is:

$$I_S = S \cdot \Theta_p + \varepsilon$$

In which error =

$$I_{OE} + I_{OT}(T_A) + \varepsilon_S \cdot \Theta_p \cdot S + \varepsilon_L(\Theta_{Pmax}) \cdot \Theta_{Pmax} \cdot S + TCS \cdot (T_A - 25) \cdot \Theta_p \cdot S$$

- With:
- $\Theta_p = N_p \cdot I_p$: primary current linkage (At)
 - Θ_{Pmax} : max primary current linkage applied to the transducer
 - I_S : secondary current (A)
 - T_A : ambient operating temperature (°C)
 - I_{OE} : electrical offset current (A)
 - $I_{OT}(T_A)$: temperature variation of I_O at temperature T_A (°C)
 - S : sensitivity of the transducer (A/At)
 - TCS : temperature coefficient of S
 - ε_S : sensitivity error
 - $\varepsilon_L(\Theta_{Pmax})$: linearity error for Θ_{Pmax}

This model is valid for primary ampere-turns Θ_p between $-\Theta_{Pmax}$ and $+\Theta_{Pmax}$ only.

Sensitivity and linearity

To measure sensitivity and linearity, the primary current (DC) is cycled from 0 to I_{PN} , then to $-I_{PN}$ and back to 0 (equally spaced $I_{PN}/10$ steps). The sensitivity S is defined as the slope of the linear regression line for a cycle between $\pm I_{PN}$.

The sensitivity error ε_S is defined as the error between the measured sensitivity S_S and the theoretical sensitivity, expressed in % of the theoretical sensitivity.

The linearity error ε_L is the maximum positive or negative difference between the measured points and the associated linear regression line at a given primary current, expressed in % of I_{PN} .

Magnetic offset

The magnetic offset current I_{OM} is the consequence of a current on the primary side ("memory effect" of the transducer's ferromagnetic parts). It is measured using the following primary current cycle. I_{OM} depends on the current value I_{P1} ($I_{P1} > I_{PM}$).

$$I_{OM} = \frac{I_S(t_1) - I_S(t_2)}{2} \cdot \frac{1}{S}$$

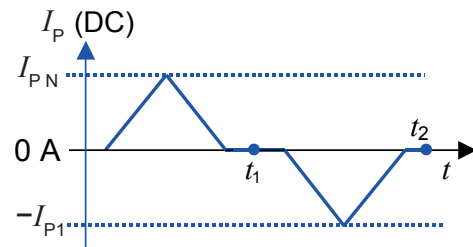


Figure 8: Current cycle used to measure magnetic and electrical offset (transducer supplied)

Performance parameters definition (continued)

Electrical offset

The electrical offset current I_{OE} can be measured when the ferro-magnetic parts of the transducer are:

- completely demagnetized (which is difficult to realize)
- or in a known magnetization state, like in the current cycle shown in figure 8.

Using the current cycle shown in figure 8, the electrical offset is:

$$I_{OE} = \frac{I_s(t_1) + I_s(t_2)}{2}$$

The temperature variation I_{OT} of the electrical offset current I_{OE} is the variation of the electrical offset from 25 °C to the considered temperature:

$$I_{OT}(T) = I_{OE}(T) - I_{OE}(25\text{ °C})$$

Note: the transducer has to be demagnetized prior to the application of the current cycle (for example with a demagnetization tunnel).

Total error

The total error ϵ_{tot} is the error at $\pm I_{PN}$, relative to the rated value I_{PN} . The total error ϵ_{tot} at 25 °C includes the electrical offset, the magnetic offset, the sensitivity error and the linearity error, expressed in % of I_{PN} .

The formula for total error ϵ_{tot} is:

$$\epsilon_{tot} \text{ at } I_p = \left(\frac{I_{out} \text{ at } I_p}{S_N} - I_{p.ref} \right) \times \frac{100}{I_{PN}} \text{ [in \% of } I_{PN}]$$

Error

The error ϵ is defined as the simple error for each measured point at a given primary current without taking into account the electrical offset, expressed in % of I_{PN} .

The formula for error ϵ is:

$$\epsilon \text{ at } I_p = \epsilon_s \text{ at } I_p - I_{OE} \text{ referred to primary [in \% of } I_{PN}]$$

Delay times

The delay time t_{D90} and the delay time t_{D10} are shown in figure 9. Both depend on the primary current di/dt . They are measured at nominal ampere-turns.

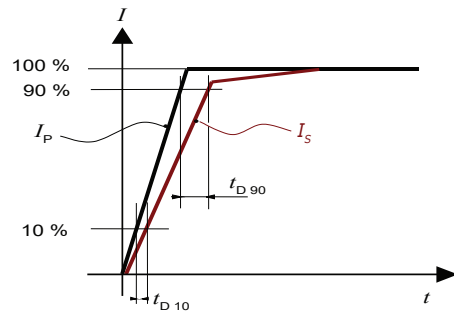


Figure 9: t_{D10} (delay time @ 10 %) and t_{D90} (delay time @ 90 %)

Safety

This transducer must be used in limited-energy secondary circuits according to IEC 61010-1.



This transducer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the manufacturer's operating instructions.

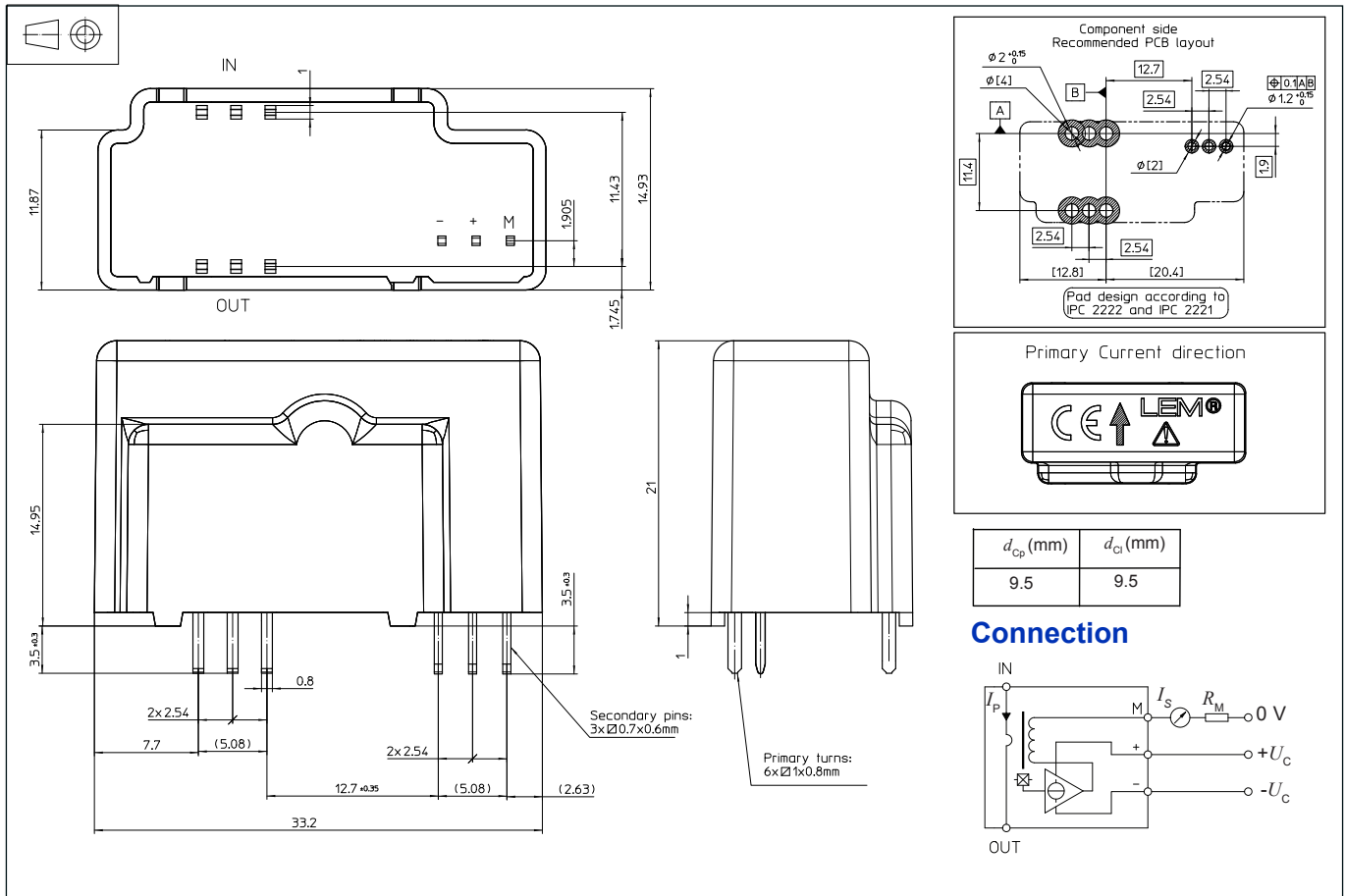


Caution, risk of electrical shock

When operating the transducer, certain parts of the module can carry hazardous voltage (eg. primary busbar, power supply). Ignoring this warning can lead to injury and/or cause serious damage.

This transducer is a build-in device, whose conducting parts must be inaccessible after installation.

A protective housing or additional shield could be used. Main supply must be able to be disconnected.

Dimensions LH 50-P (in mm)


| Number of primary turns | Primary current | | Nominal output current I_{SN} [mA] | Turns ratio N_S | Primary resistance R_P [m Ω] | Primary insertion inductance L_P [μ H] |
|-------------------------|-------------------------|----------------------|---|----------------------|---|--|
| | nominal I_{PN} [A] | maximum I_P [A] | | | | |
| 1 | 50 | 110 | 25 | 1 : 2000 | 0.08 | 0.007 |

Mechanical characteristics

- General tolerance ± 0.2 mm
- Fastening & connection of primary
Recommended PCB hole 2 mm
- Fastening & connection of secondary
Recommended PCB hole 1.2 mm

Remarks

- I_s is positive when I_p flows from terminals "IN" to terminals "OUT".
- The jumper temperature and PCB should not exceed 100 °C.
- This is a standard model. For different versions (supply voltages, turns ratios, unidirectional measurements...), please contact us
- Installation of the transducer must be done unless otherwise specified on the datasheet, according to LEM Transducer Generic Mounting Rules. Please refer to LEM document N°ANE120504 available on our Web site: <https://www.lem.com/en/file/3137/download/>.